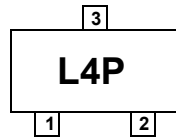
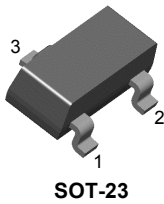
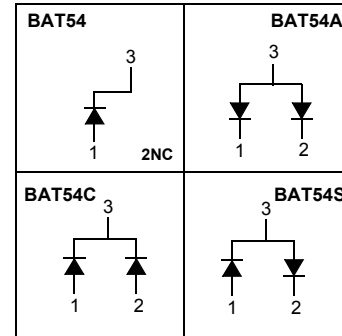


# BAT54/A/C/S Schottky Diodes



**MARKING**  
BAT54 = L4P BAT54A = L42  
BAT54C = L43 BAT54S = L44

### Connection Diagram



### Absolute Maximum Ratings \* $T_a = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Unit
$V_{RRM}$	Maximum Repetitive Reverse Voltage	30	V
$I_{F(AV)}$	Average Rectified Forward Current	200	mA
$I_{FSM}$	Non-repetitive Peak Forward Surge Current Pulse Width = 1.0 second	600	mA
$T_{STG}$	Storage Temperature Range	-55 to +150	$^\circ\text{C}$
$T_J$	Operating Junction Temperature	-55 to +150	$^\circ\text{C}$

\* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

### Thermal Characteristics

Symbol	Parameter	Value	Unit
$P_D$	Power Dissipation	290	mW
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	430	$^\circ\text{C}/\text{W}$

### Electrical Characteristics $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Conditions	Min.	Max.	Units
$V_R$	Breakdown Voltage	$I_R = 10\mu\text{A}$	30		V
$V_F$	Forward Voltage	$I_F = 0.1\text{mA}$ $I_F = 1\text{mA}$ $I_F = 10\text{mA}$ $I_F = 30\text{mA}$ $I_F = 100\text{mA}$		240 320 400 500 0.8	mV mV mV mV V
$I_R$	Reverse Leakage	$V_R = 25\text{V}$		2	$\mu\text{A}$
$C_T$	Total Capacitance	$V_R = 1\text{V}, f = 1.0\text{MHz}$		10	pF
$t_{rr}$	Reverse Recovery Time	$I_F = I_R = 10\text{mA}, I_{RR} = 1.0\text{mA}, R_L = 100\Omega$		5.0	ns

## Typical Performance Characteristics

Figure 1. Forward Voltage vs Temperature

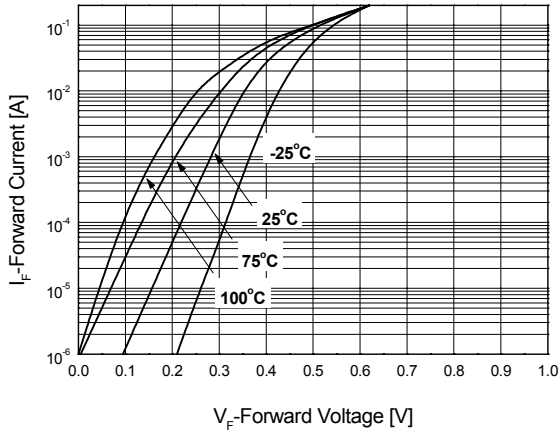


Figure 2. Reverse Leakage Current vs Temperature

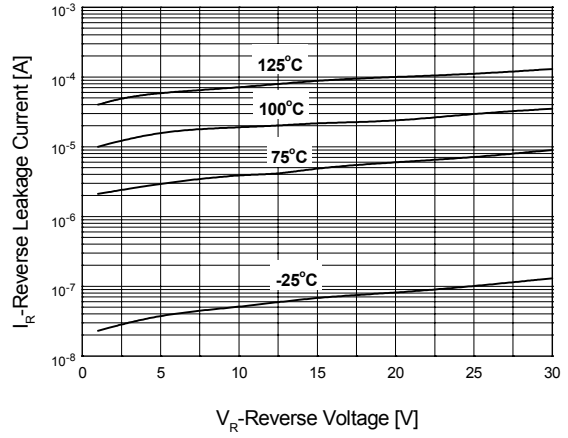
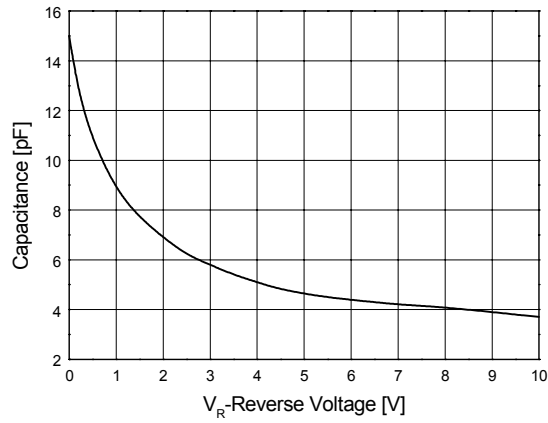


Figure 3. Capacitance vs Reverse Bias Voltage



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E <sup>2</sup> CMOS™	I <sup>2</sup> C™	MSX™	QT Optoelectronics™	TinyLogic <sup>®</sup>
EnSigna™	i-Lo™	MSXPro™	Quiet Series™	TINYOPTO™
FACT™	ImpliedDisconnect™	OCX™	RapidConfigure™	TruTranslation™
FACT Quiet Series™		OCXPro™	RapidConnect™	UHC™
Across the board. Around the world.™		OPTOLOGIC <sup>®</sup>	μSerDes™	UltraFET <sup>®</sup>
The Power Franchise <sup>®</sup>		OPTOPLANAR™	SILENT SWITCHER <sup>®</sup>	UniFET™
Programmable Active Droop™		PACMAN™	SMART START™	VCX™

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